

3^{ième} partie :

Sharp Phase Field Method

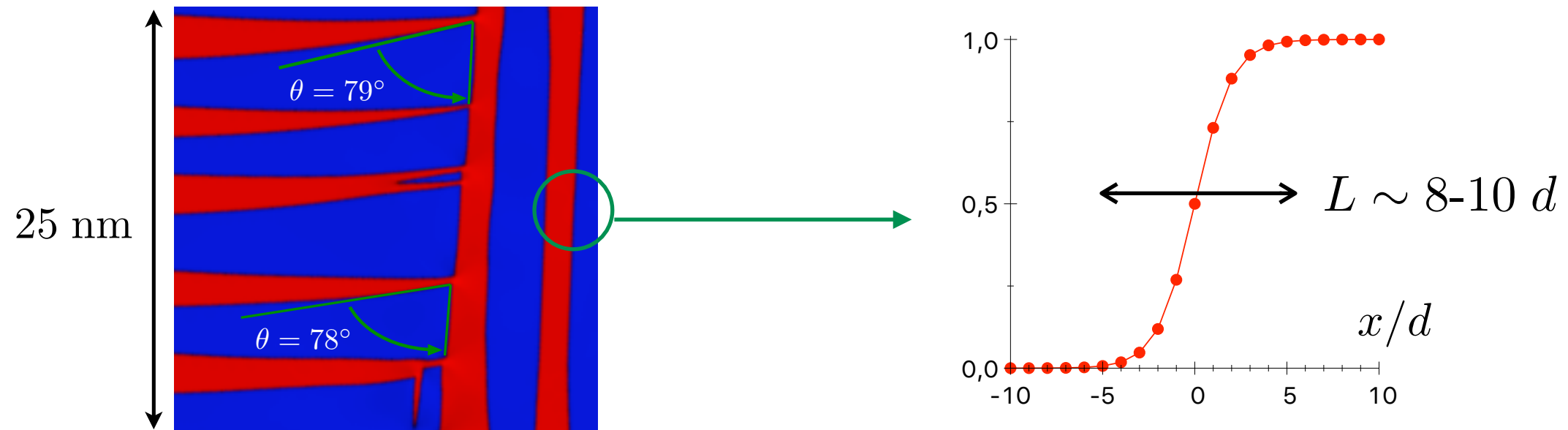
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“Classical” Phase Field Method

Continuous formulation $\longrightarrow$ diffuses interfaces !!! :



- Numerics : discrete grid, grid spacing d
- No pinning : $d \ll L \longrightarrow$ limitation on accessible linear dimension
- 3D simulations computationally intensive

What we want :

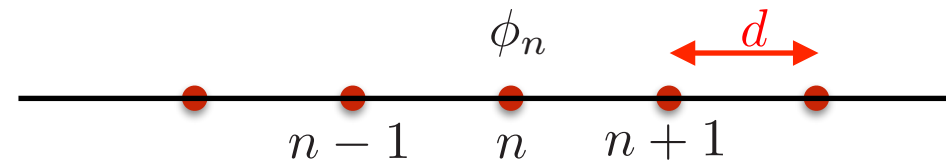
- A phase field method with sharp interfaces on a grid with a finite grid spacing
- with no pinning on the grid, even if the interface thickness l and grid spacing d are such that : $l \ll d$
- Ideally : interface width reduced to only one grid point !

The Sharp Phase Field pour Method (S-PFM)

Finel et al, PRL (2018)

A discrete formulation !

Consider a 1D lattice :



Discrete free energy functional :

$$F = \sum_n \left\{ g(\phi_n) + \frac{1}{2} \lambda (\phi_{n+1} - \phi_n)^2 \right\}$$

Interface at equilibrium : $\frac{\delta F}{\delta \phi_n} = 0$

$$g'(\phi_n) - \frac{\lambda}{d^2} (\phi_{n+1} + \phi_{n-1} - 2\phi_n) = 0 \quad \text{Eq. I}$$

→ Question :

$\exists? g(\phi)$ such that, if $\phi_n = f(nd)$ is the equilibrium profil, $f(nd - x_0)$ is also an equilibrium profil $\forall x_0 \in \mathbb{R}$?

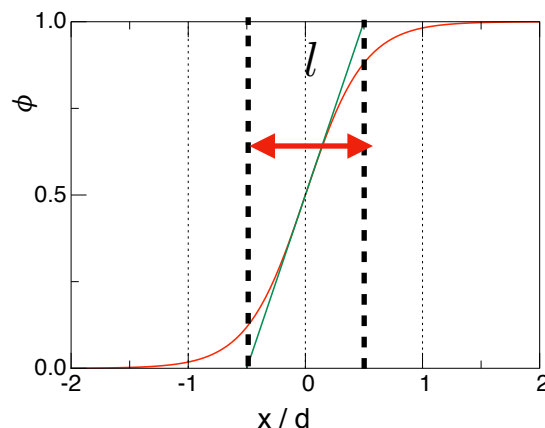
→ Procedure :

• look for a function $f(x)$ such that, if $\phi_n = f(nd - x_0)$, $(\phi_{n+1} + \phi_{n-1} - 2\phi_n)$ is function of ϕ_n independent of x_0 !!!

• i.e. look for a function $f(x)$ such that, if $\phi_n = f(nd - x_0)$, Eq. I becomes an ODE independent of x_0 !!!

→ Choice :

$$f(x) = \frac{1}{2} \left(1 + \tanh \frac{2x}{l} \right)$$



Then : $2\phi_{n\pm 1} - 1 = \frac{(2\phi_n - 1) \pm \alpha}{1 \pm (2\phi_n - 1)\alpha}$

$$\alpha = \tanh\left(\frac{2d}{l}\right)$$

Eq. I :

$$g'(\phi) = \frac{\lambda}{d^2} \left\{ \frac{1 - \alpha^2}{1 - \alpha^2(2\phi - 1)^2} - 1 \right\} (2\phi - 1)$$

Solution :

$$g(\phi) = \frac{\lambda}{4d^2} \left\{ \frac{\alpha^2 - 1}{\alpha^2} \log[1 - \alpha^2(1 - 2\phi)^2] - (1 - 2\phi)^2 \right\}$$

The Sharp Phase Field pour Method (S-PFM)

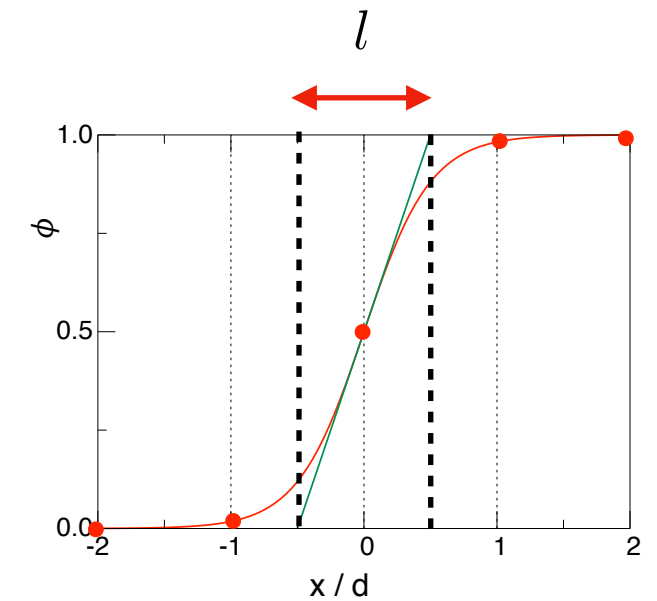
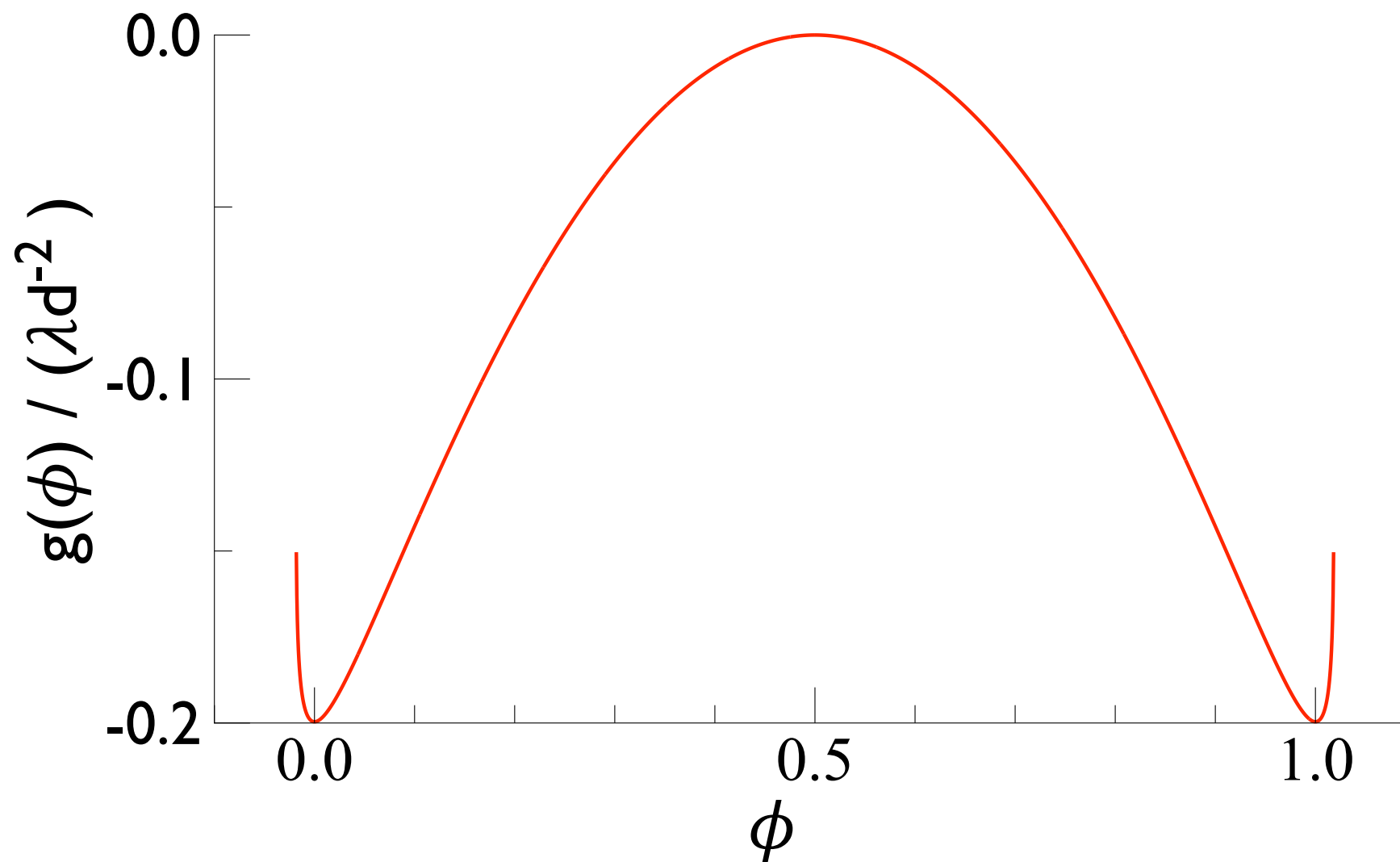
Landau potential

$$g(\phi) = \frac{\lambda}{4d^2} \left\{ \frac{\alpha^2 - 1}{\alpha^2} \log[1 - \alpha^2(1 - 2\phi)^2] - (1 - 2\phi)^2 \right\}$$

$$\alpha = \tanh\left(\frac{2d}{l}\right)$$

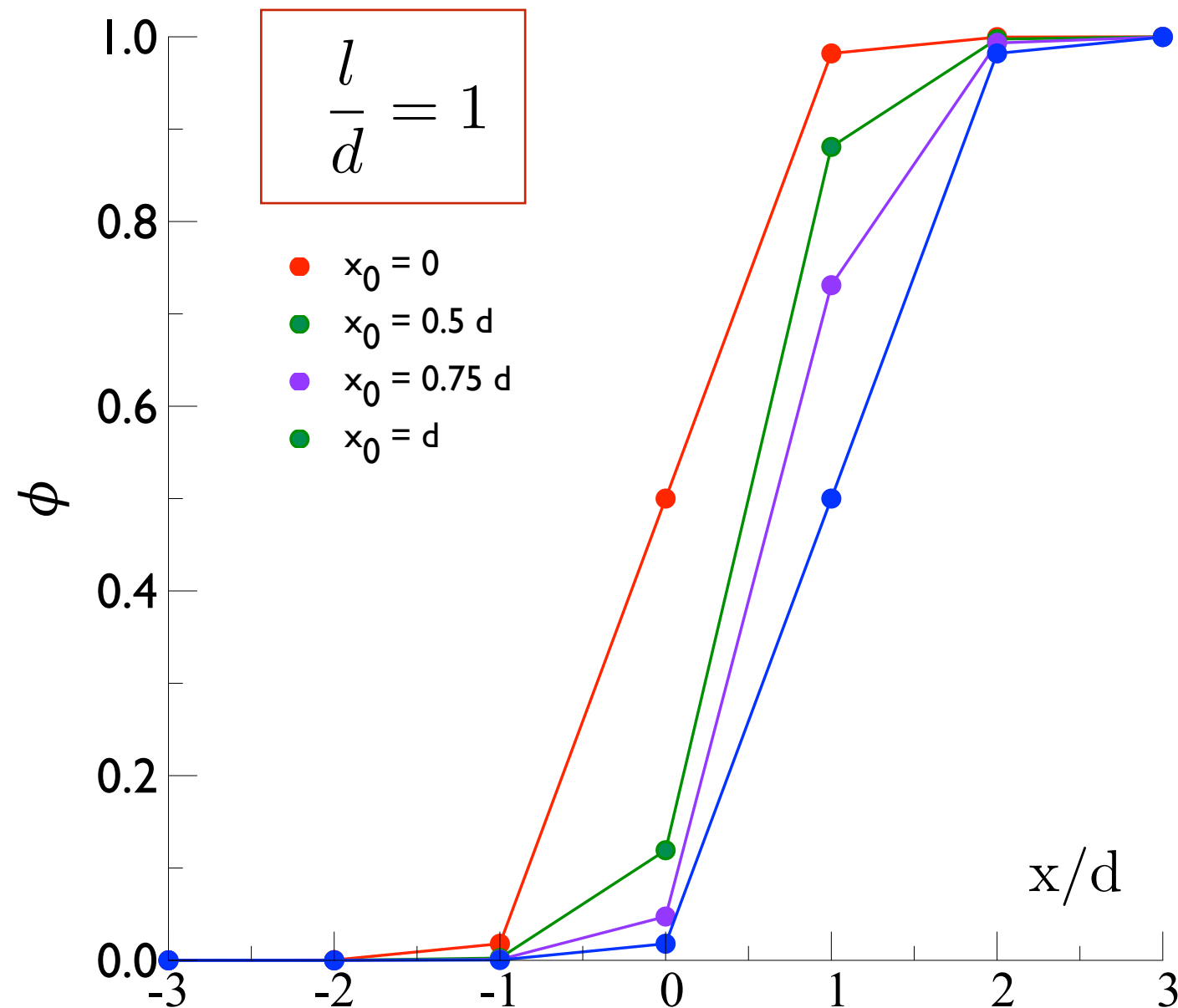
→ Exemple :

$$\frac{l}{d} = 1$$



The Sharp Phase Field pour Method (S-PFM)

no pinning even for sharp interfaces



→ same interface energy (10^{-14}) : $\sigma_{int} \simeq 0.44263 \lambda d^{-1}$

→ interface energy is exactly invariante by translation !

S-PFM in 3D

2D - 3D :

- no solution $g(\phi)$ such that σ_{int} is *exactly* invariant by translation along all directions
- no way to recover exact translational and rotational invariances on a discrete lattice

→ we proceed as follows :

- select a plane family $(h_1 k_1 l_1)$ along which we impose continuous translational invariance
- to recover rotational invariance, select $(n - 1)$ other families $(h_2 k_2 l_2) \dots (h_n k_n l_n)$ and impose :

$$\sigma(h_1 k_1 l_1) = \sigma(h_2 k_2 l_2) = \dots = \sigma(h_n k_n l_n) \quad \text{Eq. I}$$

- need $(n - 1)$ degrees of freedom
- extend gradient terms to n^{th} neighbours, with weighting coefficients γ_i !

$$F = \sum_{\vec{r}} \left\{ g(\phi(\vec{r})) + \frac{\lambda}{2} \sum_{i=1}^n \gamma_i \frac{\nu_i}{d_i^2} \sum_{k=1}^{m_i} \|\phi(\vec{r} + \vec{r}_i(k)) - \phi(\vec{r})\|^2 \right\}$$

$$\sum_{i=1}^n \gamma_i = 1$$

$$d_i = \|\vec{r}_i(\cdot)\|$$

$$\nu_i = \frac{3}{m_i}$$

- look for a $g(\phi)$ and weighting coefficients $\{\gamma_1, \dots, \gamma_{n-1}\}$ to fulfil Eq. I and translational invariance along $(h_1 k_1 l_1)$
- solution :

$$g(\phi) = \frac{\lambda}{4} \sum_{i=1}^3 \gamma_i \frac{\nu_i}{d_i^2} \sum_{k=1}^{m_i} \left\{ \frac{\alpha_i(\vec{r}_i(k))^2 - 1}{\alpha_i(\vec{r}_i(k))^2} \log[1 - \alpha_i(\vec{r}_i(k))^2 (2\phi - 1)^2] - (2\phi - 1)^2 \right\}$$

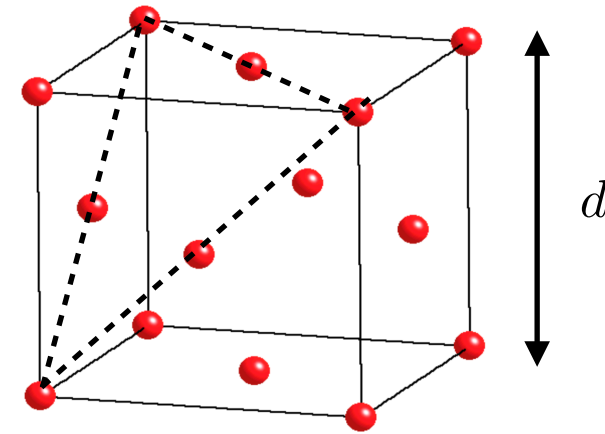
$$\alpha_i(\vec{r}_i(k)) = \tanh\left(\frac{\vec{r}_i(k) \cdot \vec{u}}{w}\right)$$

$\vec{u}$: unitary vector perpendicular to planes $(h_1 k_1 l_1)$

S-PFM on FCC grid

Why FCC grid ?

- maximise isotropy
- adapted to elastic solvers for discrete elastic fields



→ strategy for choosing plane family (h_1, k_1, l_1) that receives continuous translational invariance :

- maximise the inter-reticular distance between planes : $(h_1 k_1 l_1) = (111)$

→ to minimise pinning along other directions !

→ for rotational invariance :

- select 2 other families : $(h_2 k_2 l_2) = (200)$ and $(h_3 k_3 l_3) = (220)$
- extend gradient terms up to 3rd neighbours
- optimisation procedure on the weighting terms γ_2 and γ_3 of the gradient terms :

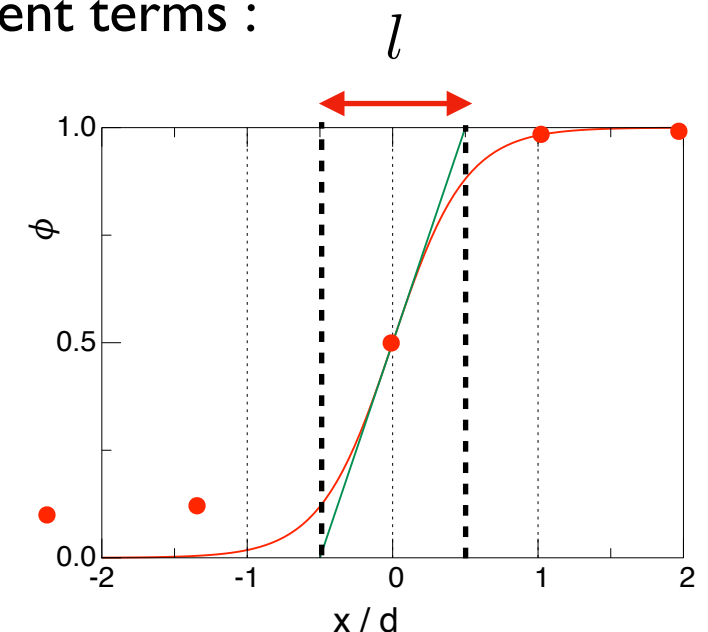
for $\frac{l}{d} = \frac{2}{3}$ → we get :

γ_2	0.1736
γ_3	0.2545

$\sigma(111)$	0.671991
$\sigma(200)$	0.671989
$\sigma(220)$	0.671990

(units: λd^{-2})

$$\frac{\Delta\sigma}{\sigma} \simeq 2 \cdot 10^{-6} !$$



Quality of the S-PFM (I)

growth of a single precipitate

free energy density

$$g_{tot}(\phi) = g(\phi) - \Delta F h(\phi)$$

kinetics

$$\frac{\partial \phi}{\partial t} = -L \frac{\delta F}{\delta \phi} = -L \left\{ g'(\phi) - \frac{\lambda}{d^2} \tilde{\nabla}^2 \phi \right\}$$

$$\Delta F > 0$$

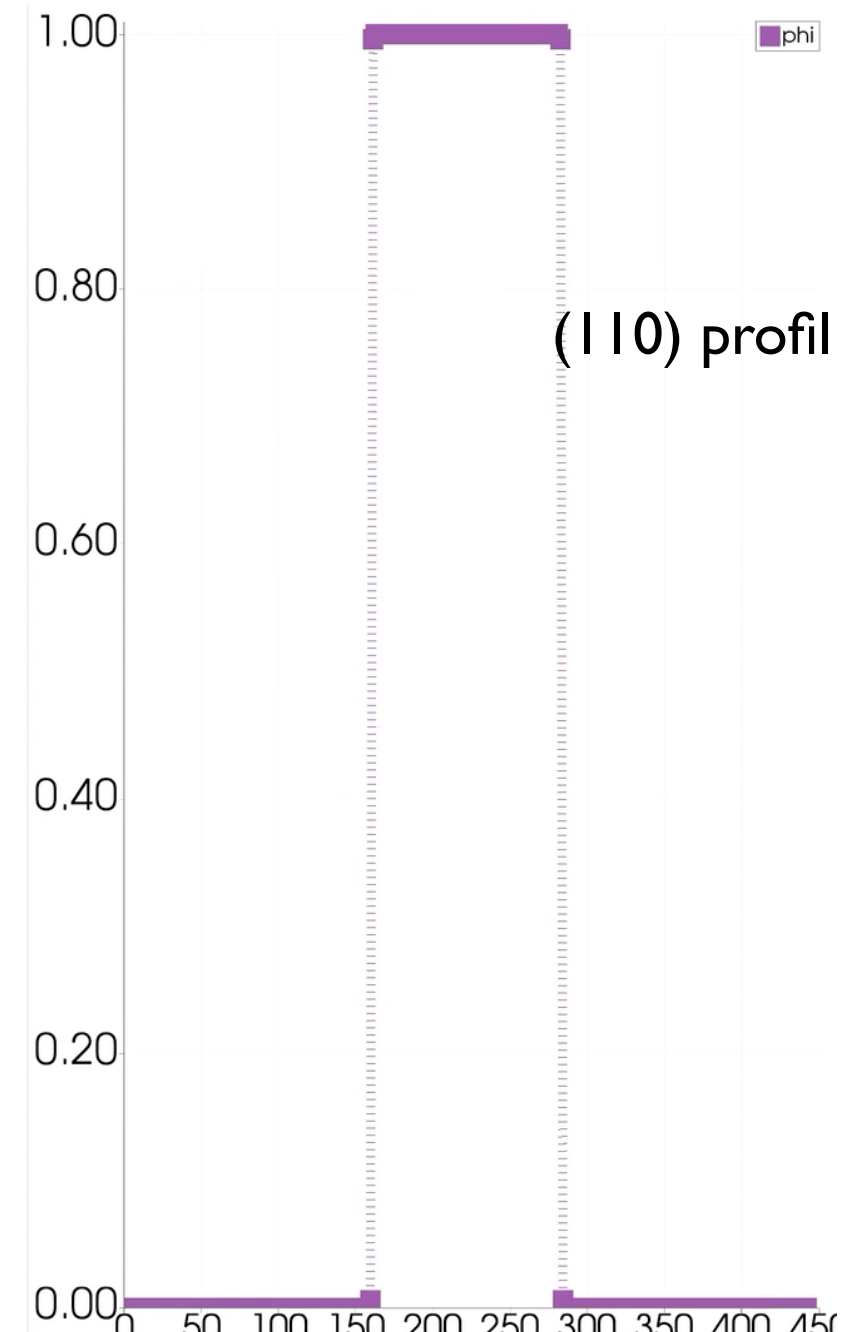
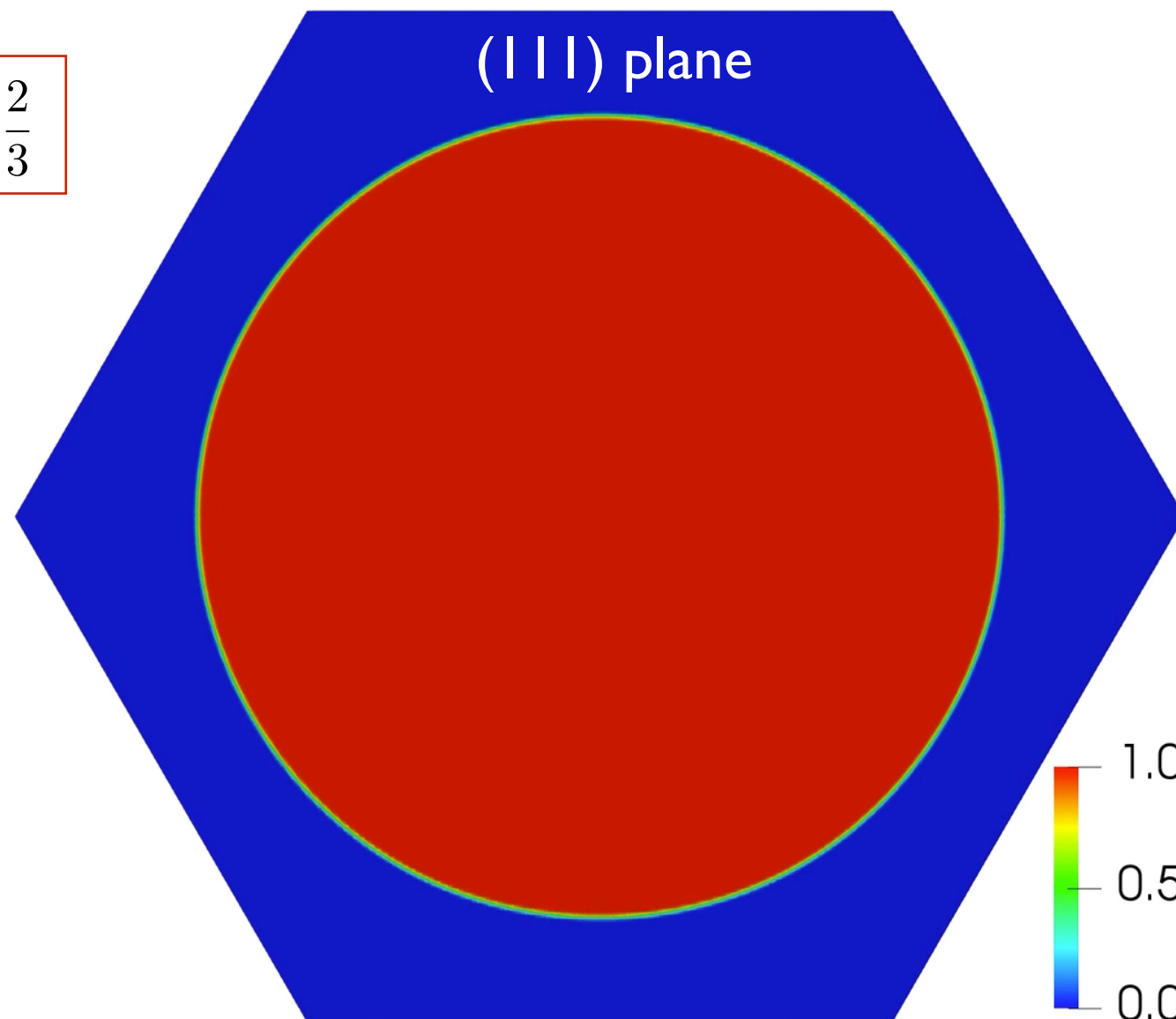
$$h(\phi) = 3\phi^2 - 2\phi^3$$

precipitate : $\phi = 1$

matrice : $\phi = 0$

simulation : 256x256x256

$$\frac{l}{d} = \frac{2}{3}$$

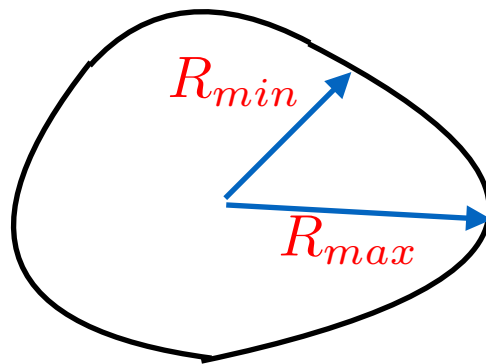


Quality of the S-PFM (2)

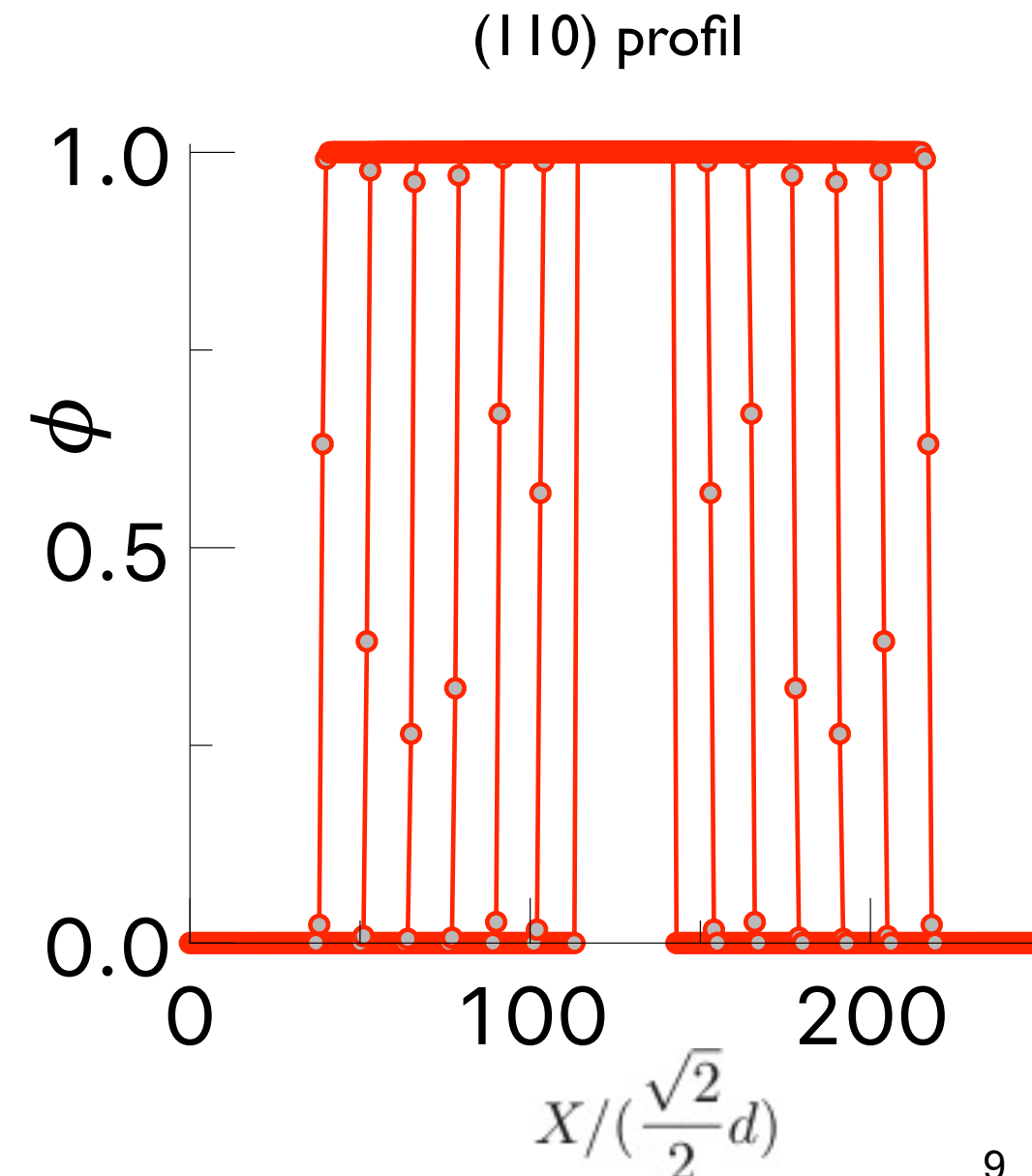
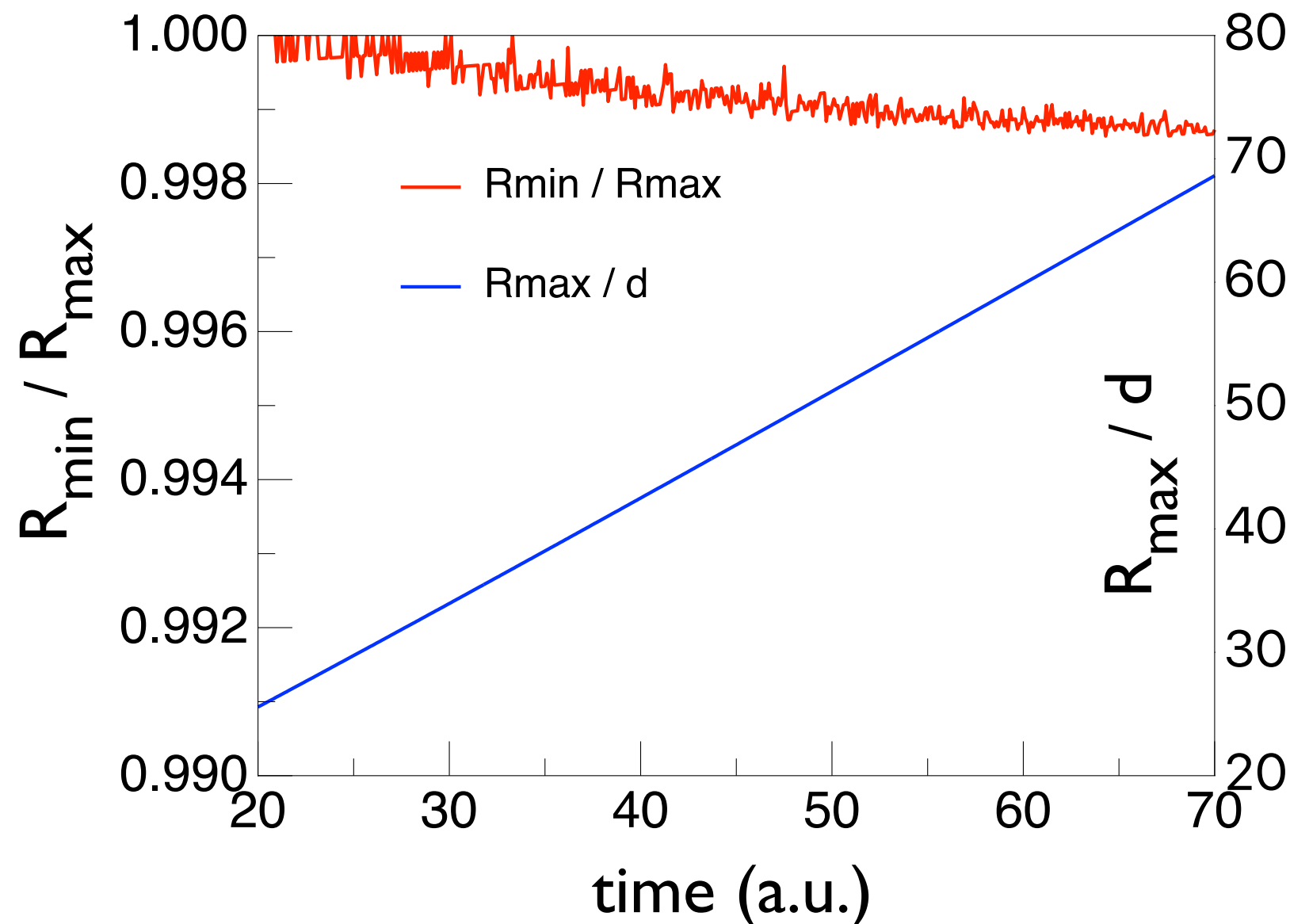
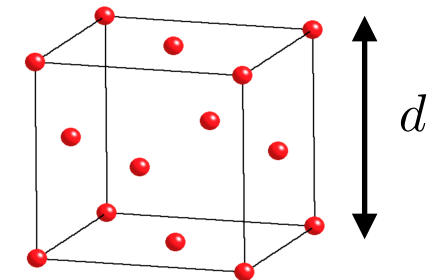
Sphericity criteria to test the rotational invariance :

a growing precipitate :

$$\frac{l}{d} = 1$$



$$\frac{R_{min}}{R_{max}}$$

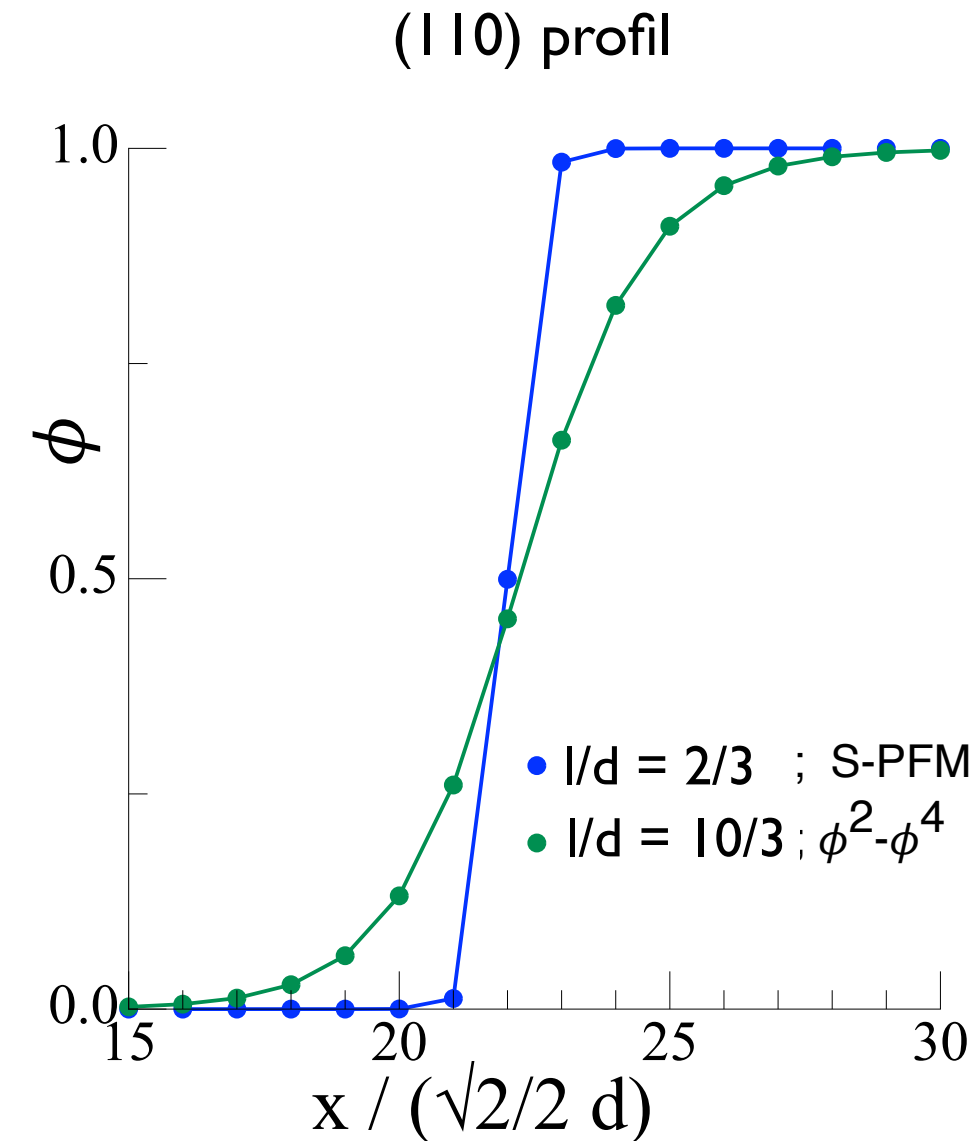
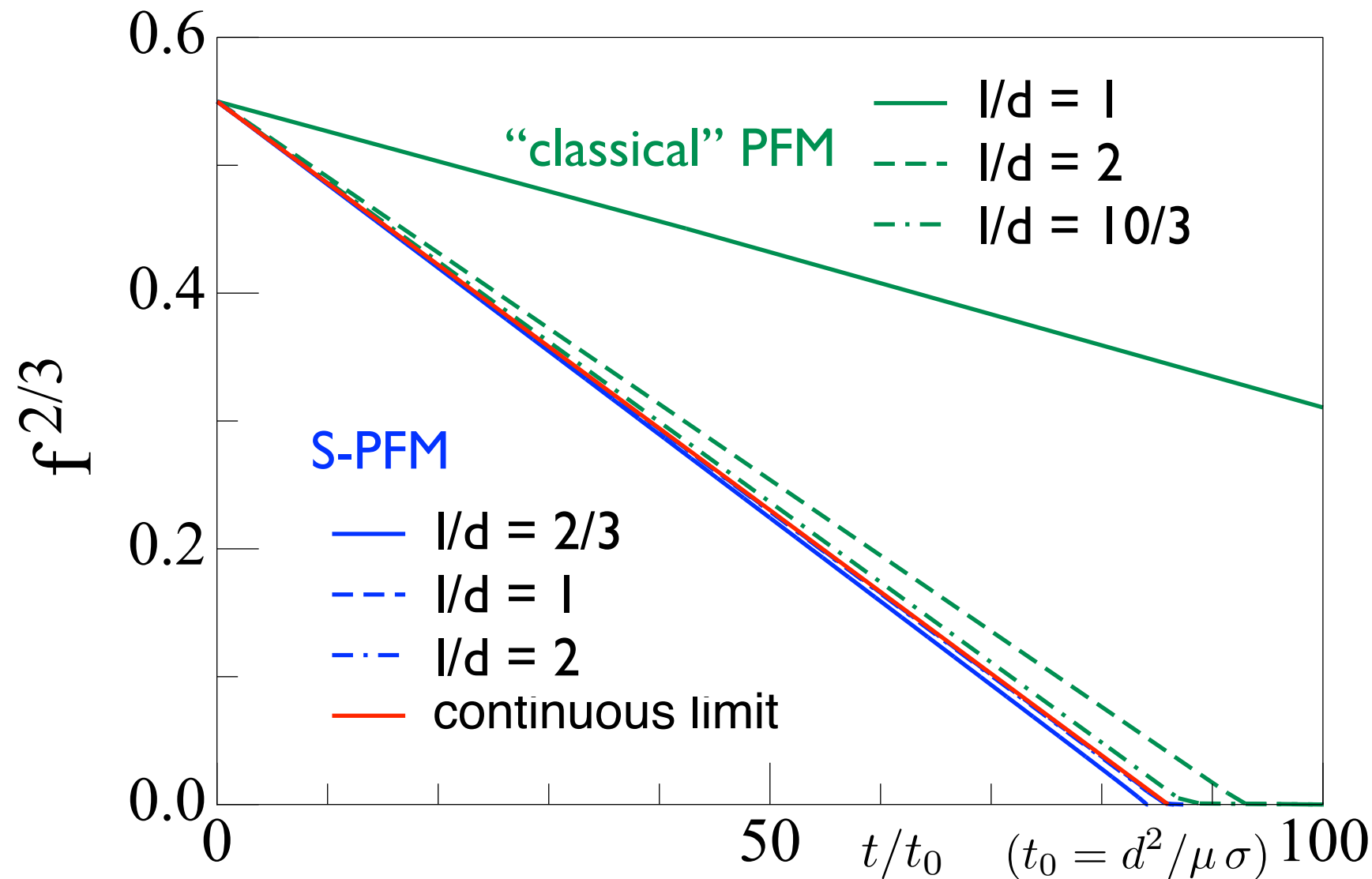


Interfacial kinetic properties :

ability of S-PFM to reproduce the “exact” interfacial kinetics

Curvature-driven collapse of a single precipitate :

→ comparison S-PFM / “classical” PFM :



→ For a precision on the interface velocity of env. 1.7% :

S-PFM : $l/d = 2/3$	→	1 grid point in the interface
“classical” PFM : $l/d = 10/3$	→	8 grid points in the interface

S-PFM with a conserved order-parameter (concentration)

→ free energy density :

$$f(c, \phi) = g(\phi) + \frac{\lambda}{2} \|\nabla_d \phi\|^2 + f_{chem}(c, \phi, \nabla c) \quad \|\nabla_d\|^2 : \text{S-PFM extended gradient term}$$

→ kinetics :

$$\begin{aligned} \frac{\partial c}{\partial t} &= M \nabla^2 \frac{\partial f_{chem}(c, \phi)}{\partial c} \\ \frac{\partial \phi}{\partial t} &= -L \left\{ g'(\phi) - \lambda \Delta_d \phi - \frac{\partial f_{chem}(c, \phi)}{\partial \phi} \right\} \end{aligned}$$

→ but :

- coupling between c and ϕ may play a rôle into the interface profil
- look for a $f_{chem}(c, \phi, \nabla c)$ such that a planar interface keeps the S-PFM interface profil even in c and ϕ are coupled !

→ solution :

$$\begin{aligned} f_{chem}(c, \phi) &= h(\phi) f_1(c_1) + (1 - h(\phi)) f_2(c_2) \\ c &= h(\phi) c_1 + (1 - h(\phi)) c_2 \\ \text{state variables : } c \text{ and } \phi \end{aligned}$$

$$\begin{aligned} c &= h(\phi) c_1 + (1 - h(\phi)) c_2 \\ \frac{\partial f_1(c_1)}{\partial c_1} &= \frac{\partial f_2(c_2)}{\partial c_2} \end{aligned}$$



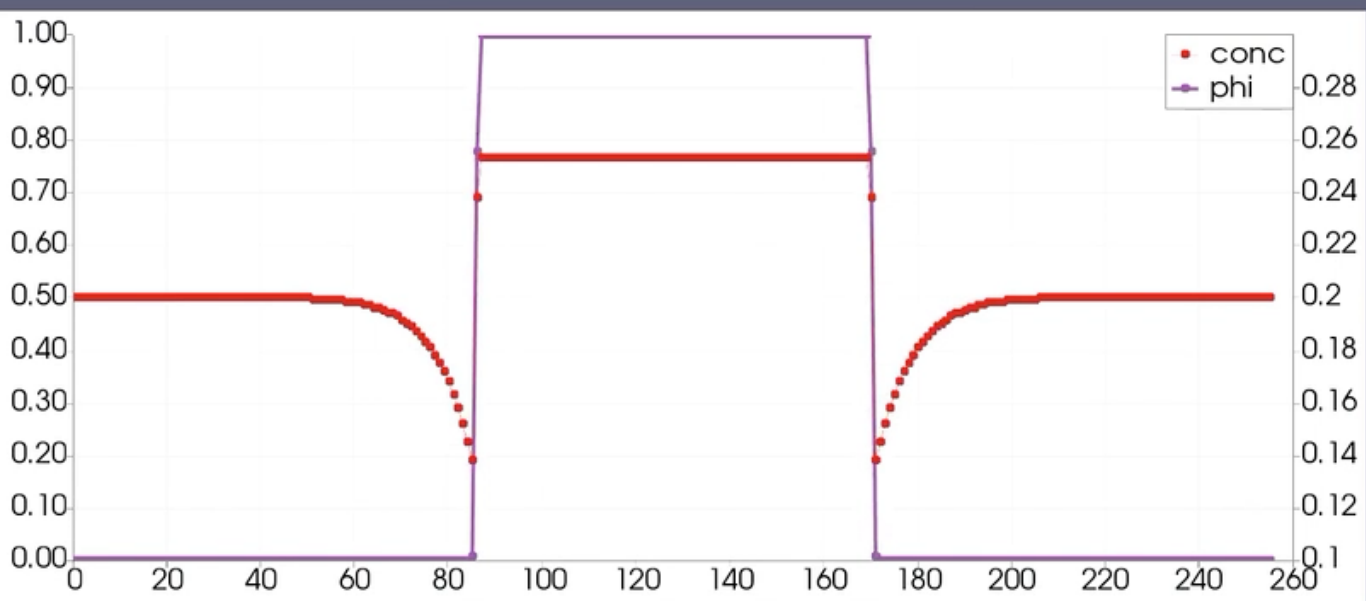
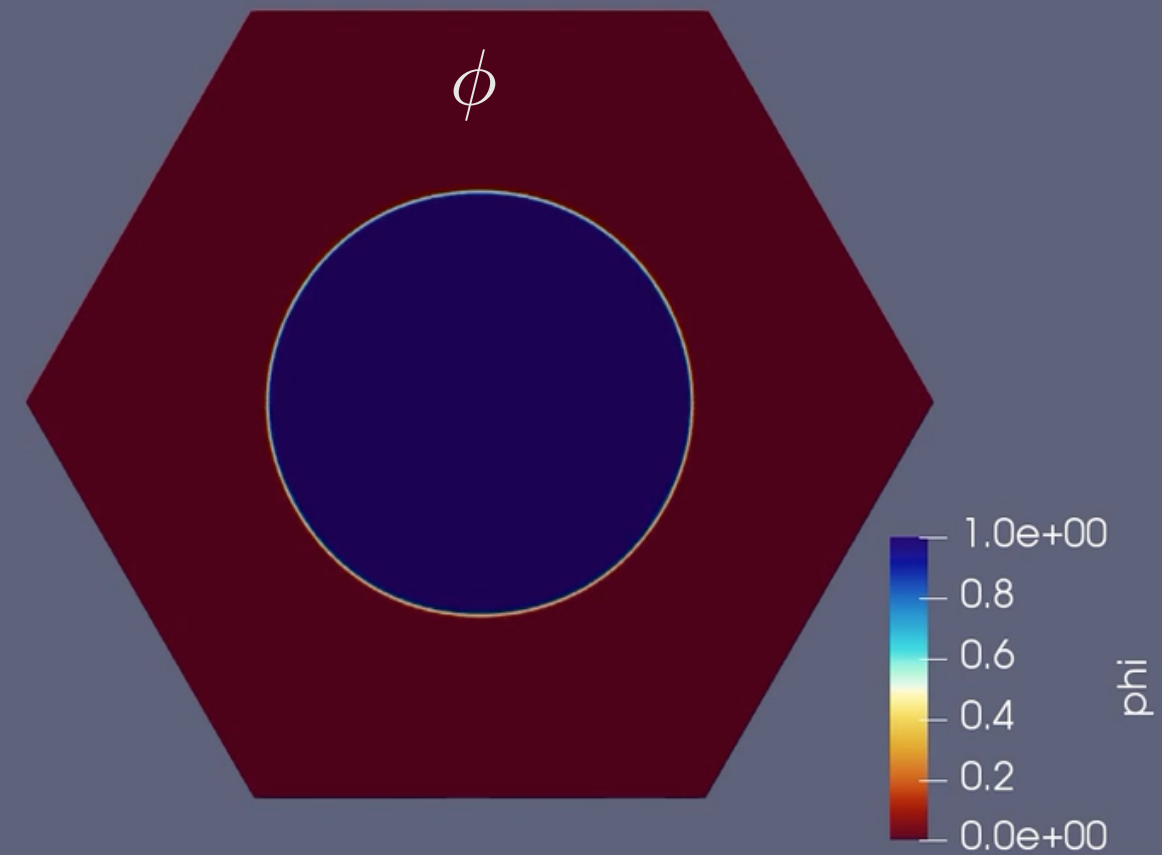
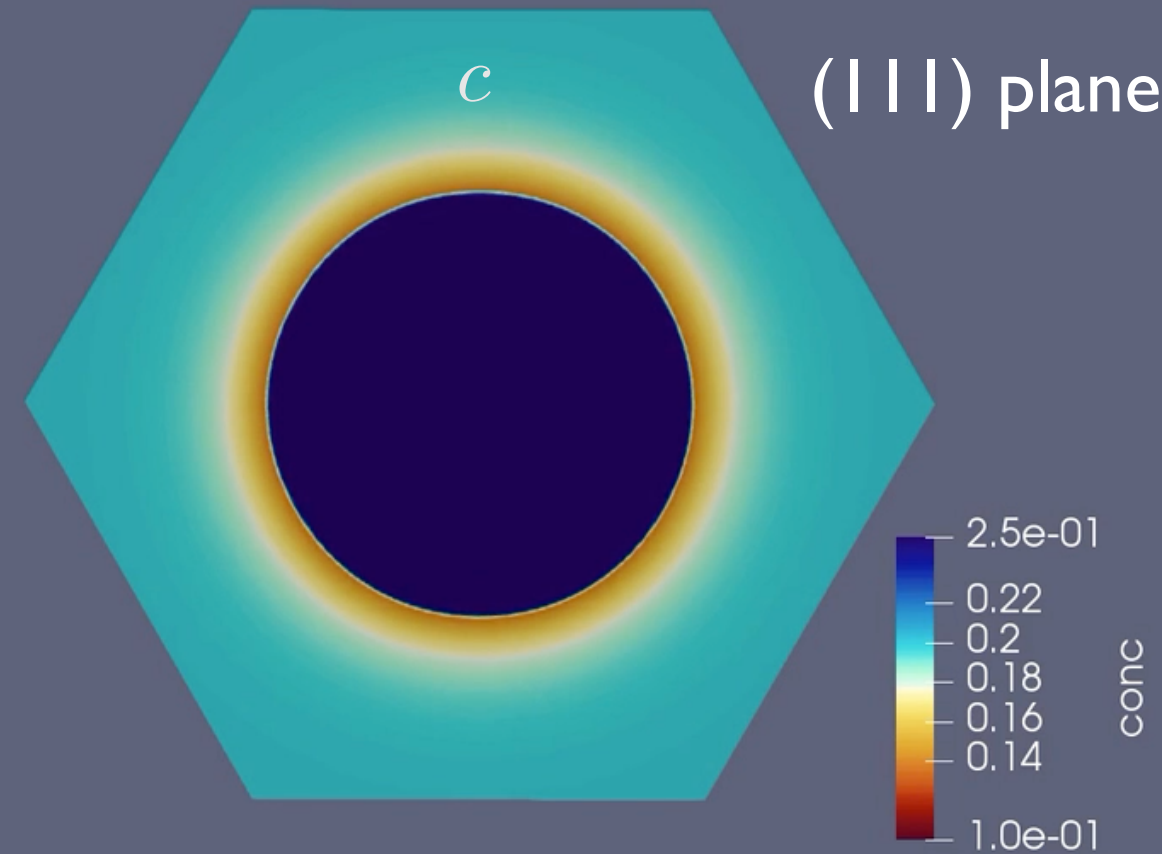
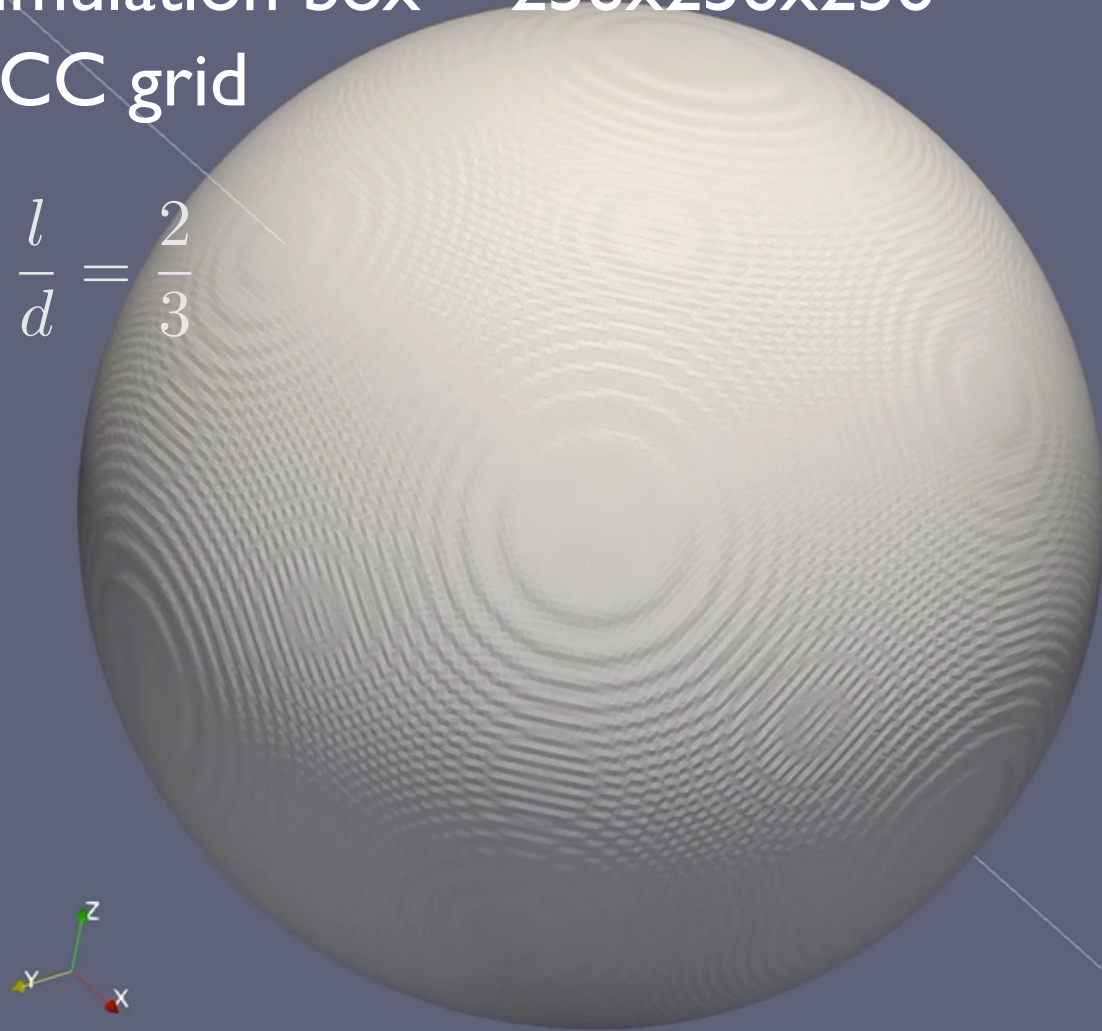
$$\begin{aligned} c_1 &= c_1(c, \phi) \\ c_2 &= c_2(c, \phi) \end{aligned}$$

S-PFM with a conserved order parameter

Simulation box = 256x256x256

FCC grid

$$\frac{l}{d} = \frac{2}{3}$$



S-PFM with a conserved order parameter and elastic fields

Inhomogeneous elasticity :

$$\frac{l}{d} = 1$$

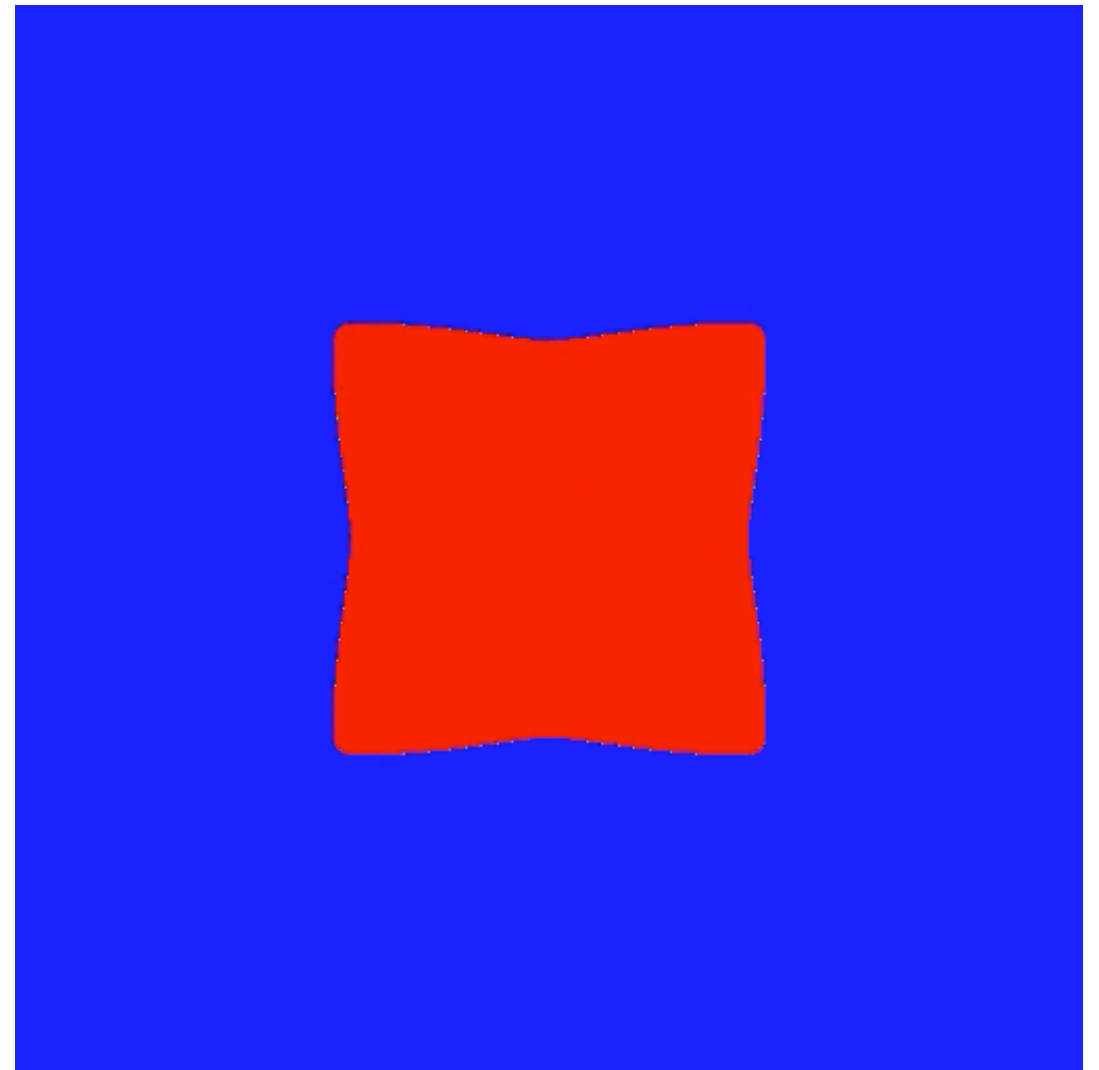
$$\gamma \quad \begin{array}{lcl} C_{11} & = & 197 \text{ GPa} \\ C_{12} & = & 144 \text{ GPa} \\ C_{44} & = & 90 \text{ GPa} \end{array}$$

$$\gamma' \quad \begin{array}{lcl} C_{11} & = & 193 \text{ GPa} \\ C_{12} & = & 113 \text{ GPa} \\ C_{44} & = & 132 \text{ GPa} \end{array}$$

concentration field



phase field

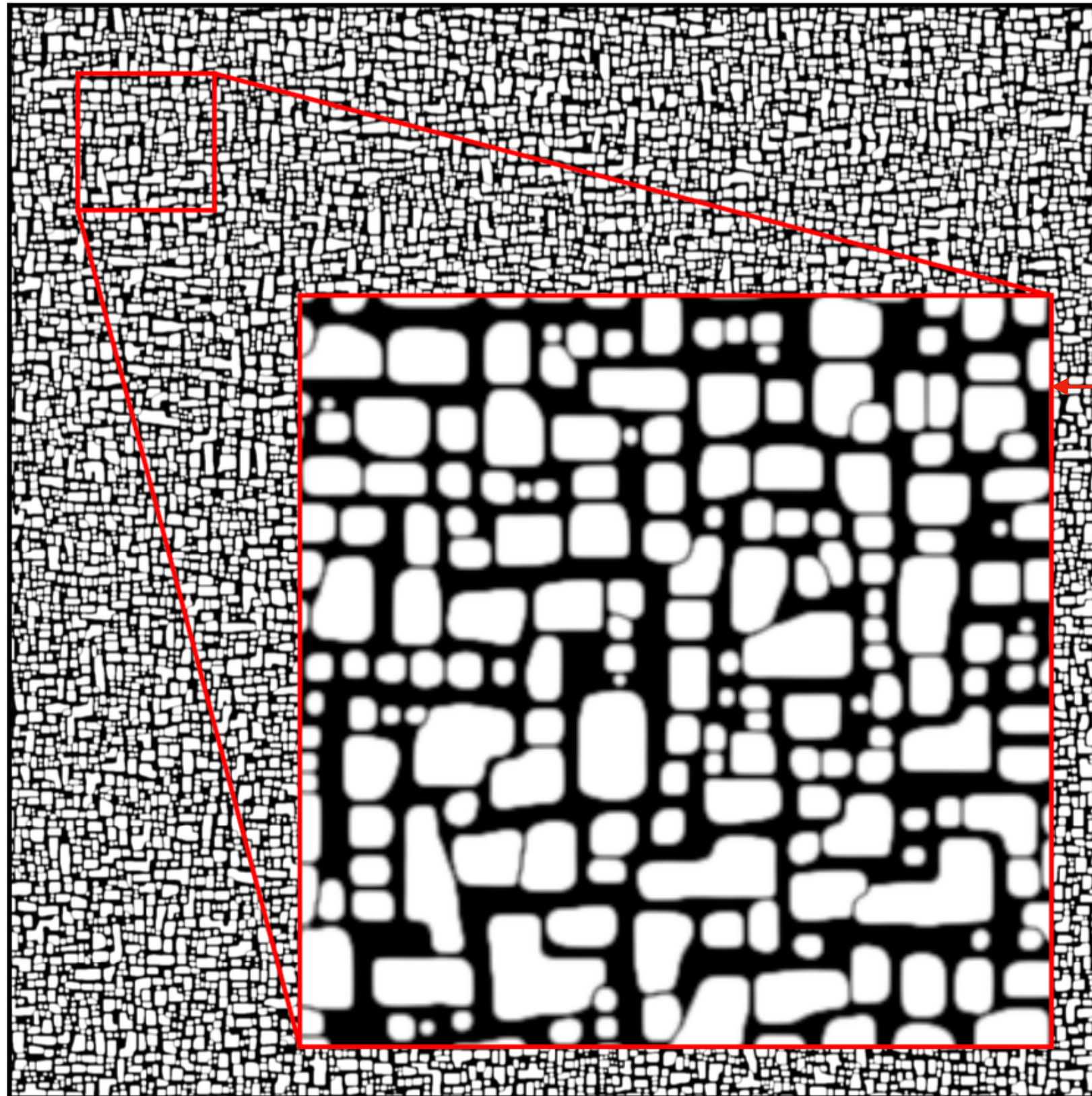


Microstructures in Ni-based super-alloys

S-PFM

2048x2048

M. Degeiter, PhD, 2019



”classical” PFM

2048x2048

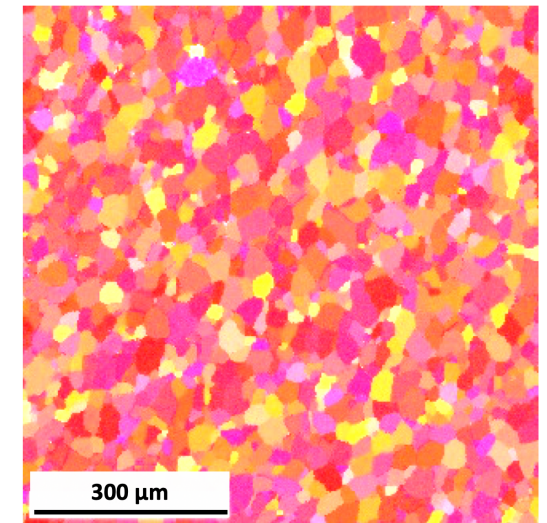
S-PFM : a multi-phase field extension for polycrystals (I)

Grain growth by “classical” Phase Field Method

- nbr of grains in a representative stationary state : $N \sim 3 \cdot 10^4$
- nbr of initial grains needed to reach this stage : $N_0 \sim 3 \cdot 10^5$
- interface thickness $\ll$ grain sizes : $l \sim D/10$
- grid step $\ll$ interface width : $d \sim l/10$

→ nbr of voxels $\sim 10^{12}$

Ni - 14%W ; 100 °C - 10 mn

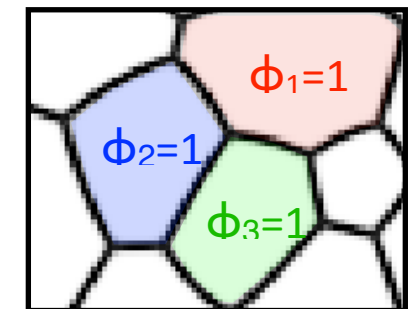


Polycrystalline grain growth is one of the most important microstructure evolutions in engineering processes.

A multi-phase field S-PFM : (Dimokrati et al, Acta Mat., 2020)

$$F = V_d \sum_{\mathbf{r}} \Delta f \left[\sum_i g(\phi_i) + \gamma \sum_{i>j} \phi_i^2 \phi_j^2 \right] + \frac{\kappa}{2} \sum_i |\nabla^d \phi_i|^2$$

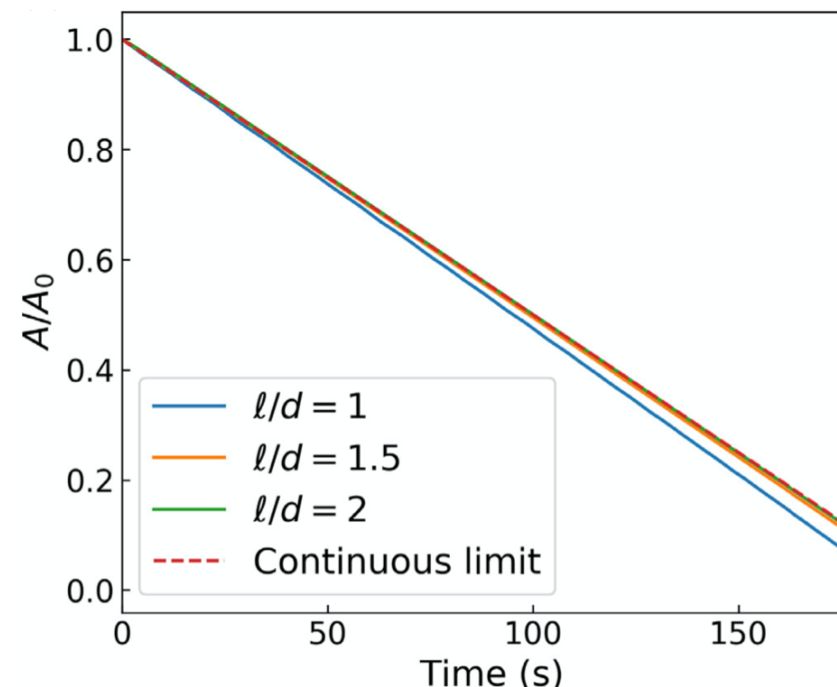
$$g(\phi) = -\frac{\phi^2}{4}(3\phi^2 - 8\phi + 6) + \frac{\kappa}{4\Delta f} \sum_s \frac{2\gamma_s}{m_x d_s^2} \sum_{k=1}^{m_s} \left[\frac{\alpha_s^2(k) - 1}{\alpha_s^2(k)} \ln [1 - \alpha_s^2(k)(2\phi - 1)^2] - (2\phi - 1)^2 \right]$$



Collapse of a circular grain :

- square grid, grid step : d
- interface thickness : l

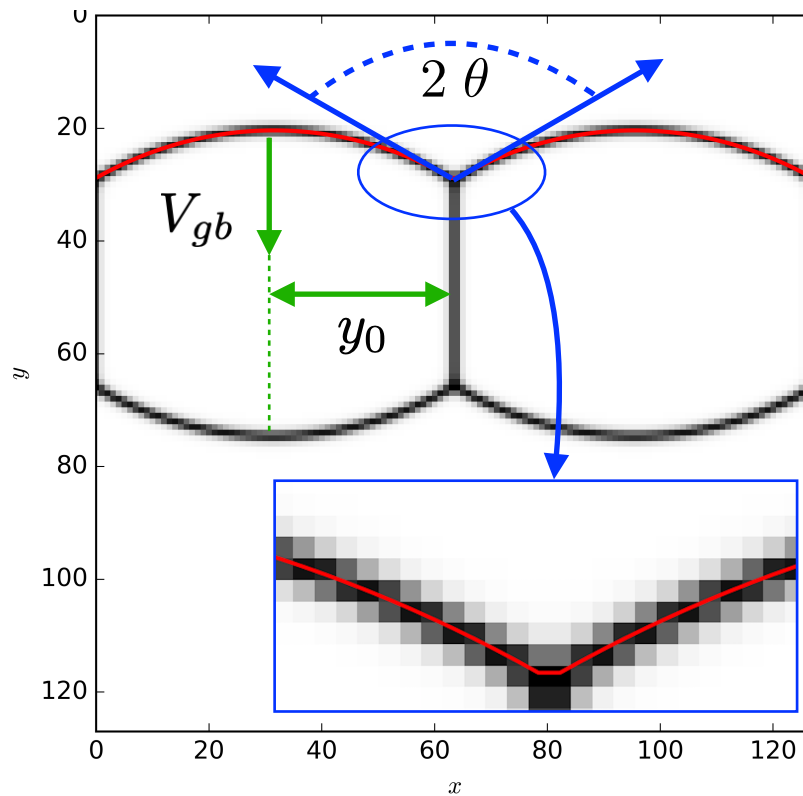
l/d	precision on slope
1	5.20 %
1.5	1.06 %
2	0.04 %



S-PFM : a multi-phase field extension for polycrystals (2)

(Dimokrati et al, Acta Mat., 2020)

Question : behaviour of triple junctions ?



— simulation
— theoretical shape :

$$y(x) = y_0 \frac{\cos^{-1}(e^{-\frac{x}{y_0}} \cos^{-1} \sin \theta)}{\cos^{-1} \sin \theta}$$

Triple junction properties
(when no junction drag)

	theory	S-PFM
θ	$\pi/3$	$60.25 \pm 0.25^\circ$
V	$\pi/6$ (0.5236...)	0.525

(Units : $m_{gb} \sigma_{gb} y_0^{-1}$)

Statistical analysis of grain size distribution :

